NSN 5961-00-419-2908

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-419-2908 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Overall Diameter:** 1.062 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 10.0 peak negative gate voltage **Current Rating Per Characteristic:** 2.00 amperes source cutoff current minor **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0